

Isc N-Channel MOSFET Transistor

FCPF650N80Z

• FEATURES

- With TO-220F package
- Low input capacitance and gate charge
- Low gate input resistance
- ESD improved capability
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• APPLICATIONS

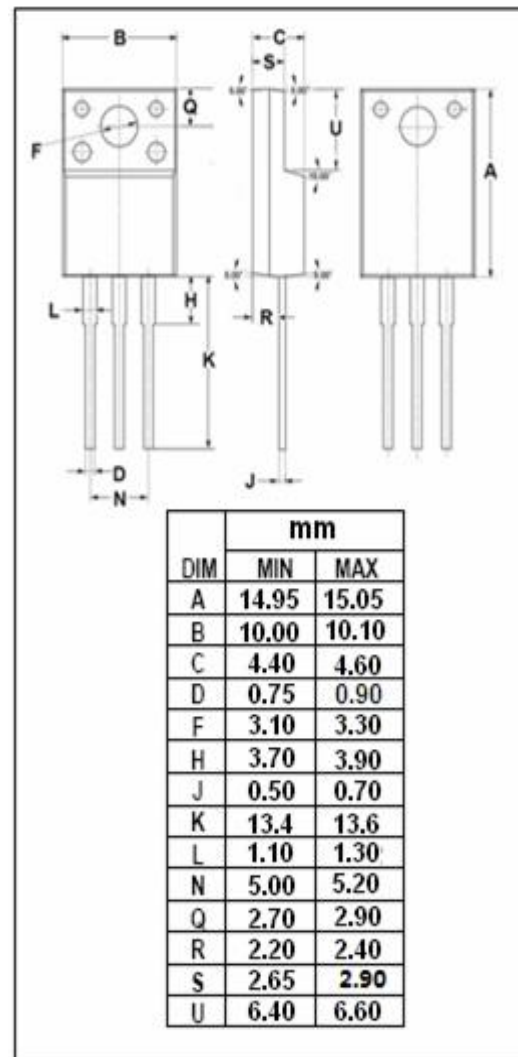
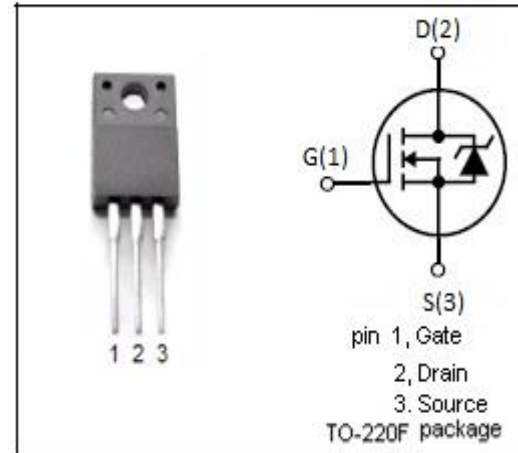
- Switching applications
- Load switch
- Power management

• ABSOLUTE MAXIMUM RATINGS(T_a=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	800	V
V _{GSS}	Gate-Source Voltage	±30	V
I _D	Drain Current-Continuous T _c =25°C T _c =100°C	10 6.3	A
I _{DM}	Drain Current-Single Pulsed	24	A
P _D	Total Dissipation @T _c =25°C	30.5	W
T _j	Max. Operating Junction Temperature	150	°C
T _{stg}	Storage Temperature	-55~150	°C

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th(ch-c)}	Channel-to-case thermal resistance	4.1	°C/W
R _{th(ch-a)}	Channel-to-ambient thermal resistance	62.5	°C/W



Isc N-Channel MOSFET Transistor**FCPF650N80Z****ELECTRICAL CHARACTERISTICS**T_c=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 1mA	800			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D =0.8mA	2.5		4.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =4A		0.53	0.65	Ω
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V; V _{DS} = 0V			± 10	μ A
I _{DSS}	Drain-Source Leakage Current	V _{DS} =800V; V _{GS} = 0V; T _c =25°C V _{DS} =640V; V _{GS} = 0V; T _c =125°C			25 250	μ A
V _{SDF}	Diode forward voltage	I _{SD} =8A, V _{GS} = 0 V			1.2	V

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